1N4016 THRU 1N4020

1.0 AMP SILICON RECTIFIERS

FEATURES

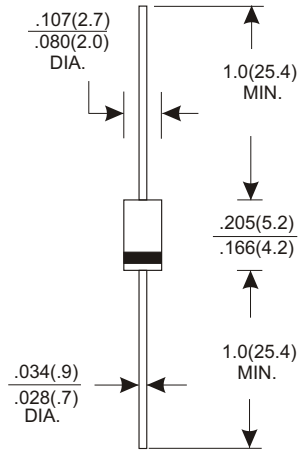
* Low forward voltage drop
* High current capability
* High reliability
* High surge current capability

MECHANICAL DATA

* Case: Molded plastic
* Epoxy: UL 94V-0 rate flame retardant
* Lead: Axial leads, solderable per MIL-STD-202, method 208 guranteed
* Polarity: Color band denotes cathode end
* Mounting position: Any

VOLTAGE RANGE
1600 to 2000 Volts
CURRENT
1.0 Ampere

DO-41



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating 25°C ambient temperature uniess otherwies specified.
Single phase half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

TYPE NUMBER	1N4016	1N4018	1N4020	UNITS
Maximum Recurrent Peak Reverse Voltage	1600	1800	2000	V
Maximum RMS Voltage	1120	1260	1400	V
Maximum DC Blocking Voltage	1600	1800	2000	V
Maximum Average Forward Rectified Current .375"(9.5mm) Lead Length at Ta=75°C	1.0			A
Peak Forward Surge Current, 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)	30			A
Maximum Instantaneous Forward Voltage at 1.0A	1.1			V
Maximum DC Reverse Current Ta=25°C	5.0			μA
at Rated DC Blocking Voltage Ta=100°C	50			μA
Typical Junction Capacitance (Note 1)	15			pF
Typical Thermal Resistance RθJA (Note 2)	50			°C/W
Operating and Storage Temperature Range T_J, T_{STG}	-65 — +150			°C

NOTES:

1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2. Thermal Resistance from Junction to Ambient .375" (9.5mm) lead length.

RATING AND CHARACTERISTIC CURVES (1N4016 THRU 1N4020)

FIG.1-TYPICAL FORWARD CHARACTERISTICS

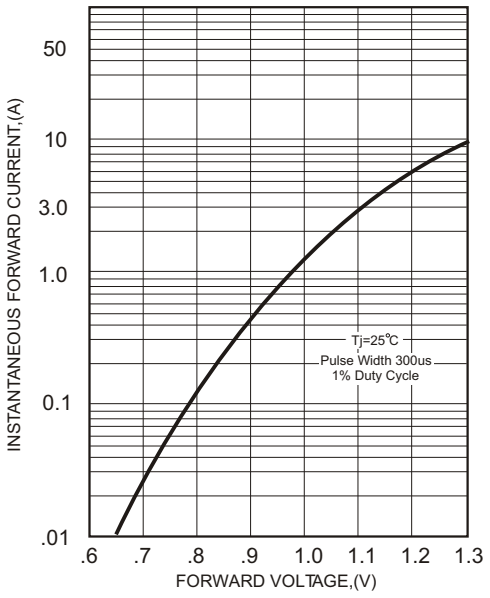


FIG.2-TYPICAL FORWARD CURRENT DERATING CURVE

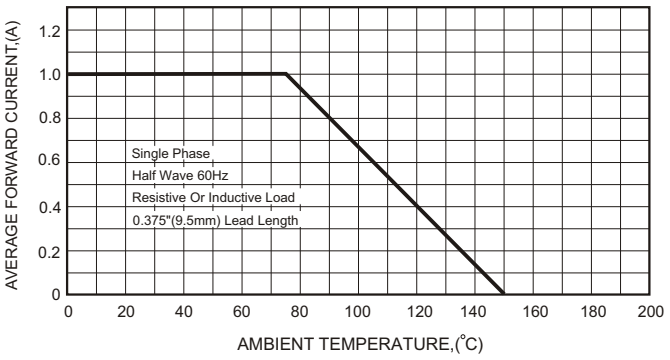


FIG.3 - TYPICAL REVERSE CHARACTERISTICS

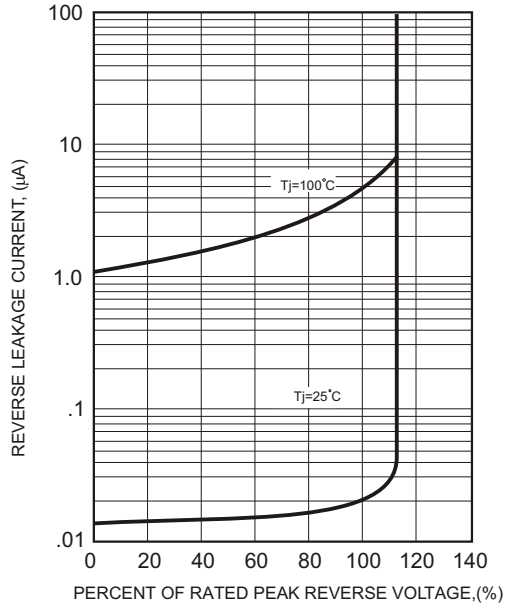


FIG.4-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

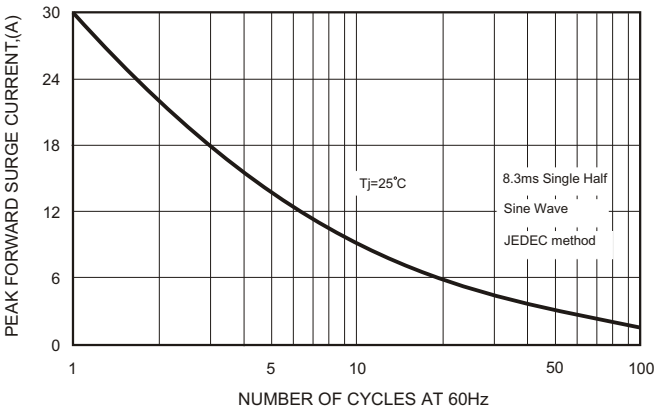


FIG.5-TYPICAL JUNCTION CAPACITANCE